

–100mA / –50V Digital transistors (with built-in resistors)

DTA114EM / DTA114EE / DTA114EUA / DTA114EKA / DTA114ESA

●Applications

Inverter, Interface, Driver

●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

●Structure

PNP epitaxial planar silicon transistor (Resistor built-in type)

●Dimensions (Unit : mm)

DTA114EM ROHM : VMT3 Abbreviated symbol : 14 Each lead has same dimensions	DTA114EE ROHM : EMT3 Abbreviated symbol : 14 Each lead has same dimensions
DTA114EUA ROHM : UMT3 EIAJ : SC-70 Abbreviated symbol : 14 Each lead has same dimensions	DTA114EKA ROHM : SMT3 EIAJ : SC-59 Abbreviated symbol : 14 Each lead has same dimensions
DTA114ESA ROHM : SPT EIAJ : SC-72 Abbreviated symbol : A114ES	

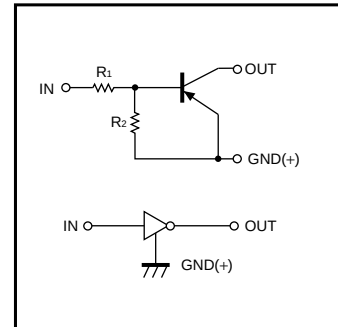
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Transistors

●Packaging specifications

Type	Package	VMT3	EMT3	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146	TP
	Basic ordering unit (pieces)	8000	3000	3000	3000	5000
DTA114EM		○	—	—	—	—
DTA114EE		—	○	—	—	—
DTA114EUA		—	—	○	—	—
DTA114EKA		—	—	—	○	—
DTA114ESA		—	—	—	—	○

●Equivalent circuit



$R_1=R_2=10k\Omega$

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits					Unit
		DTA114EM	DTA114EE	DTA114EUA	DTA114EKA	DTA114ESA	
Supply voltage	V _{CC}	-50					V
Input voltage	V _{IN}	-40 to +10					V
Output current	I _O	-50					mA
	I _{C(Max.)}	-100					
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j	150					°C
Storage temperature	T _{stg}	-55 to +150					°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	-0.5	V	$V_{CC}=-5V, I_O=-100\mu A$
	$V_{I(on)}$	-3	—	—		$V_O=-0.3V, I_O=-10mA$
Output voltage	$V_{O(on)}$	—	—	-0.3	V	$I_O/I_I=-10mA/-0.5mA$
Input current	I_I	—	—	-0.88	mA	$V_I=-5V$
Output current	$I_{O(off)}$	—	—	-0.5	μA	$V_{CC}=-50V, V_I=0V$
DC current gain	G_I	30	—	—	—	$V_O=-5V, I_O=-5mA$
Input resistance	R_I	7	10	13	$k\Omega$	—
Resistance ratio	R_2/R_1	0.8	1	1.2	—	—
Transition frequency	f_T *	—	250	—	MHz	$V_{CE}=-10V, I_E=5mA, f=100MHz$

* Characteristics of built-in transistor

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Transistors

●Electrical characteristic curves

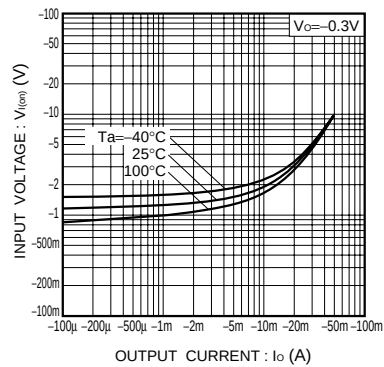


Fig.1 Input voltage vs. output current
(ON characteristics)

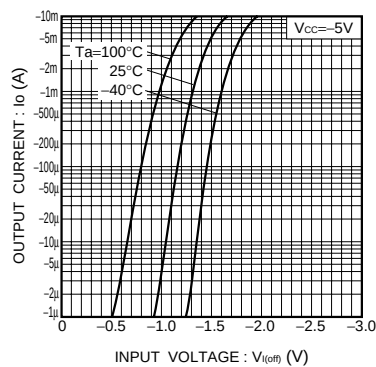


Fig.2 Output current vs. input voltage
(OFF characteristics)

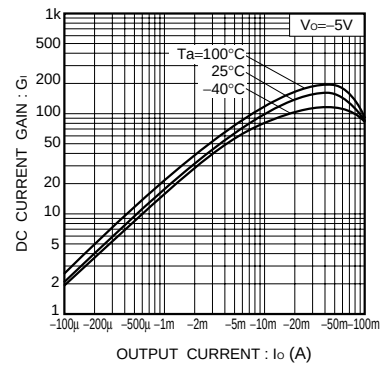


Fig.3 DC current gain vs. output
current

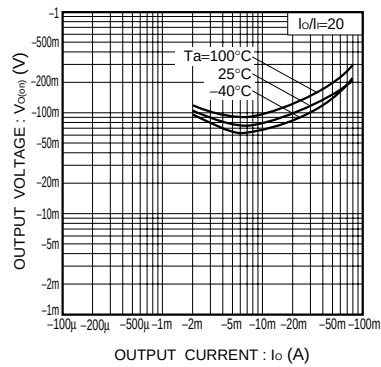


Fig.4 Output voltage vs. output current

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